

ON Semiconductor[®]

FDBL9403-F085 N-Channel PowerTrench[®] MOSFET

40 V, 240 A, 0.9 mΩ

Features

- Typical $R_{DS(on)}$ = 0.65 m Ω at V_{GS} = 10V, I_D = 80 A
- Typical Q_{g(tot)} = 144 nC at V_{GS} = 10V, I_D = 80 A
- UIS Capability
- RoHS Compliant
- Qualified to AEC Q101

Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12V Systems



MOSFET Maximum Ratings T_J = 25°C unless otherwise noted.

Symbol	Parameter		Ratings	Units
V _{DSS}	Drain-to-Source Voltage		40	V
V _{GS}	Gate-to-Source Voltage		±20	V
	Drain Current - Continuous (V _{GS} =10) (Note 1)	T _C =25°C	240	
I _D	Pulsed Drain Current	T _C = 25°C	See Figure 4	Α
E _{AS}	Single Pulse Avalanche Energy	(Note 2)	737	mJ
P _D	Power Dissipation		357	W
	Derate Above 25°C		2.38	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to + 175	°C
R _{0JC}	Thermal Resistance, Junction to Case		0.42	°C/W
R _{0JA}	Maximum Thermal Resistance, Junction to Ambient	(Note 3)	43	°C/W

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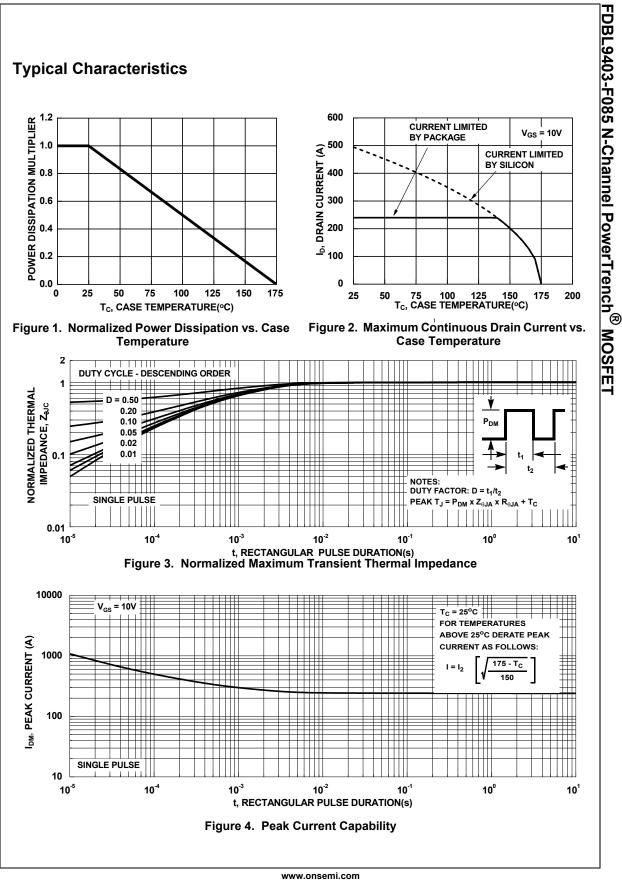
Notes:

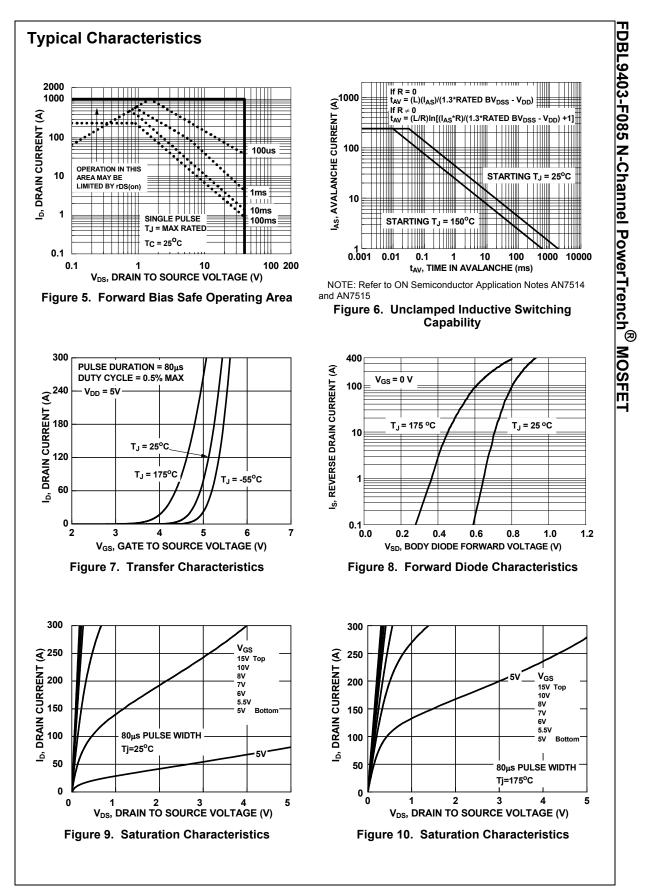
- 1: Current is limited by bondwire configuration.
- 2: Starting $T_J = 25^{\circ}C$, L = 0.36mH, $I_{AS} = 64A$, $V_{DD} = 40$ V during inductor charging and $V_{DD} = 0$ V during time in avalanche.
- 3: R_{0JA} is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{0JC} is guaranteed by design, while R_{0JA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2oz copper.

Package Marking and Ordering Information

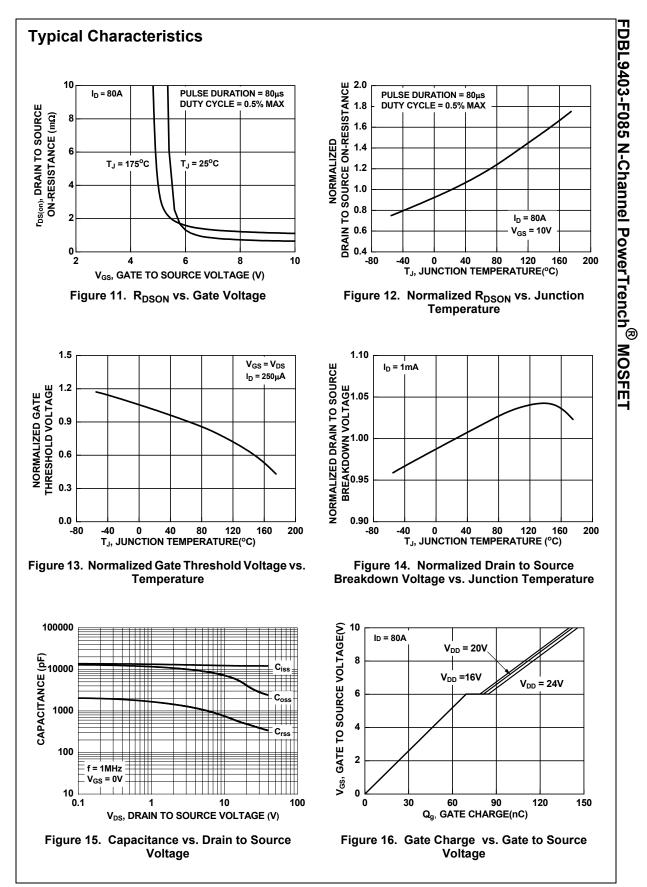
Device Marking	Device	Package			
FDBL9403	FDBL9403-F085	MO-299A	-	-	-

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
Off Cha	aracteristics						
B _{VDSS}	Drain-to-Source Breakdown Voltage	I _D = 250μA,	V _{GS} = 0V	40	-	-	V
		V_{DS} =40V, T_{J} = 25°C		-	-	1	μA
IDSS	Drain-to-Source Leakage Current	$V_{GS} = 0V$	$T_{\rm J}$ = 175°C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA
On Cha	racteristics						
V _{GS(th)}	Gate to Source Threshold Voltage	V _{GS} = V _{DS} , I _D = 250μA		2.0	3.3	4.0	V
R _{DS(on)}	Drain to Source On Resistance		T _J = 25 ^o C	-	0.65	0.90	mΩ
		V _{GS} = 10V	$T_{J} = 175^{\circ}C$ (Note 4)	-	1.10	1.50	mΩ
Dynami	ic Characteristics						
C _{iss}	Input Capacitance	– V _{DS} = 25V, V _{GS} = 0V,		-	12000	-	pF
C _{oss}	Output Capacitance	v _{DS} = 25v, f = 1MHz	v _{GS} = 0v,	-	3260	-	pF
C _{rss}	Reverse Transfer Capacitance	1 110112		-	442	-	pF
R _g	Gate Resistance	f = 1MHz		-	3.3	-	Ω
Q _{g(ToT)}	Total Gate Charge at 10V	V _{GS} = 0 to 1		-	144	188	nC
Q _{g(th)}	Threshold Gate Charge	V _{GS} = 0 to 2	V I _D = 80A	-	22	26	nC
Q _{gs}	Gate-to-Source Gate Charge			-	66	-	nC
Q _{gd}	Gate-to-Drain "Miller" Charge			-	16	-	nC
Switchi	ng Characteristics						
t _{on}	Turn-On Time			-	-	162	ns
t _{d(on)}	Turn-On Delay		-	-	42	-	ns
a(011)	Rise Time	V _{DD} = 20V,	I _D = 80A,	-	73	-	ns
tr	Turn-Off Delay	V _{GS} = 10V,		-	83	-	ns
	-		+	-	50	-	ns
t _{d(off)}	Fall Time	-				279	ns
t _{d(off)} t _f	Fall Time Turn-Off Time			-	-	210	
t <u>r</u> t _{d(off)} t _f t _{off} Drain-S				-	-	210	
t _{d(off)} t _f t _{off} Drain-S	Turn-Off Time	I _{SD} =80A, V	′ _{GS} = 0V	-	-	1.25	V
t _{d(off)} t _f t _{off} Drain-S	Turn-Off Time	I _{SD} =80A, V I _{SD} = 40A, V		-	-		V V
t _{d(off)} t _f t _{off}	Turn-Off Time	I _{SD} = 40A, \		- - - -	- - 111	1.25	





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